

N-Channel Power MOSFET

60V, 38A, 17mΩ

FEATURES

- 100% avalanche tested
- Suitable for 5V drive applications
- Pb-free plating
- RoHS compliant
- Halogen-free mold compound

KEY PERFORMANCE PARAMETERS

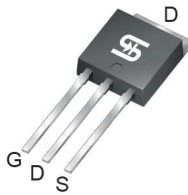
PARAMETER		VALUE	UNIT
V_{DS}		60	V
$R_{DS(on)}$ (max)	$V_{GS}=10V$	17	mΩ
	$V_{GS}=4.5V$	20	
Q_g		15	nC

APPLICATION

- SMPS Synchronous Rectification
- Networking DC-DC Power System



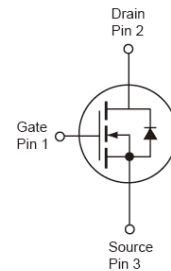
TO-251 (IPAK)



TO-251S (IPAK SL)



TO-252 (DPAK)


Notes: Moisture sensitivity level: level 3. Per J-STD-020

ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNIT
Drain-Source Voltage		V_{DS}	60	V
Gate-Source Voltage		V_{GS}	± 20	V
Continuous Drain Current (Note 1)	$T_C = 25^\circ\text{C}$	I_D	38	A
	$T_C = 100^\circ\text{C}$		24	
Pulsed Drain Current (Note 2)		I_{DM}	152	A
Single Pulsed Avalanche Energy (Note 3)		E_{AS}	20	mJ
Single Pulsed Avalanche Current (Note 3)		I_{AS}	20	A
Total Power Dissipation @ $T_C = 25^\circ\text{C}$		P_{DTOT}	46	W
Operating Junction and Storage Temperature Range		T_J, T_{STG}	- 55 to +150	$^\circ\text{C}$

THERMAL PERFORMANCE

PARAMETER	SYMBOL	LIMIT	UNIT
Junction to Case Thermal Resistance	$R_{\theta JC}$	2.7	$^\circ\text{C/W}$
Junction to Ambient Thermal Resistance	$R_{\theta JA}$	62	$^\circ\text{C/W}$

Notes: $R_{\theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistances. The case thermal reference is defined at the solder mounting surface of the drain pins. $R_{\theta JA}$ is guaranteed by design while $R_{\theta CA}$ is determined by the user's board design. $R_{\theta JA}$ shown below for single device operation on FR-4 PCB in still air

ELECTRICAL SPECIFICATIONS (T _A = 25°C unless otherwise noted)						
PARAMETER	CONDITIONS	SYMBOL	MIN	TYP	MAX	UNIT
Static ^(Note 4)						
Drain-Source Breakdown Voltage	V _{GS} = 0V, I _D = 250μA	BV _{DSS}	60	--	--	V
Gate Threshold Voltage	V _{DS} = V _{GS} , I _D = 250uA	V _{GS(TH)}	1.2	1.7	2.5	V
Gate Body Leakage	V _{GS} = ±20V, V _{DS} = 0V	I _{GSS}	--	--	±100	nA
Zero Gate Voltage Drain Current	V _{DS} = 60V, V _{GS} = 0V	I _{DSS}	--	--	1	μA
	V _{DS} = 48V, V _{GS} = 0V, T _J = 125°C		--	--	10	
Drain-Source On-State Resistance	V _{GS} = 10V, I _D = 20A	R _{DS(ON)}	--	15	17	mΩ
	V _{GS} = 4.5V, I _D = 10A		--	17.5	20	
Dynamic ^(Note 5)						
Total Gate Charge	V _{DS} = 30V, I _D = 10A, V _{GS} = 4.5V	Q _g	--	15	--	nC
Gate-Source Charge		Q _{gs}	--	5.5	--	
Gate-Drain Charge		Q _{gd}	--	5	--	
Input Capacitance	V _{DS} = 25V, V _{GS} = 0V, f = 1.0MHz	C _{iss}	--	900	--	pF
Output Capacitance		C _{oss}	--	130	--	
Reverse Transfer Capacitance		C _{rss}	--	90	--	
Gate Resistance	F = 1MHz, open drain	R _g	--	2.2	--	Ω
Switching ^(Note 6)						
Turn-On Delay Time	V _{GS} = 10V, V _{DS} = 15V, R _G = 6Ω, I _D = 1A	t _{d(on)}	--	8.6	--	ns
Turn-On Rise Time		t _r	--	24.2	--	
Turn-Off Delay Time		t _{d(off)}	--	32.3	--	
Turn-Off Fall Time		t _f	--	7.9	--	
Source-Drain Diode ^(Note 4)						
Diode Forward Voltage	V _{GS} =0V, I _S =10A	V _{SD}	--	--	1	V
Reverse Recovery Time	V _{GS} = 0V, I _S = 10A	t _{rr}	--	18	--	ns
Reverse Recovery Charge	dl _F /dt = 100A/μs	Q _{rr}	--	10	--	nC

Notes:

1. Current limited by package
2. Pulse width limited by the maximum junction temperature
3. $L = 0.1\text{mH}, I_{AS} = 20A, V_{DD} = 50V, R_G = 25\Omega$, Starting $T_J = 25^\circ\text{C}$
4. Pulse test: $PW \leq 300\mu s$, duty cycle $\leq 2\%$
5. For DESIGN AID ONLY, not subject to production testing.
6. Switching time is essentially independent of operating temperature.

ORDERING INFORMATION

PART NO.	PACKAGE	PACKING
TSM170N06CP ROG	TO-252(DPAK)	2,500pcs / 13" Reel
TSM170N06CH C5G	TO-251(IPAK)	75pcs / Tube
TSM170N06CH X0G	TO-251S(IPAK SL)	75pcs / Tube

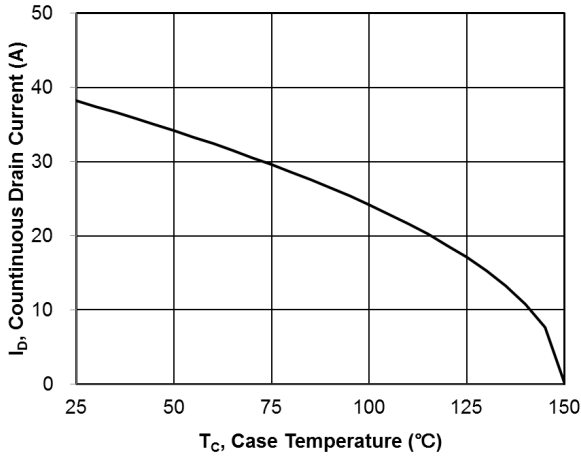
Note:

1. Compliant to RoHS Directive 2011/65/EU and in accordance to WEEE 2002/96/EC
2. Halogen-free according to IEC 61249-2-21 definition

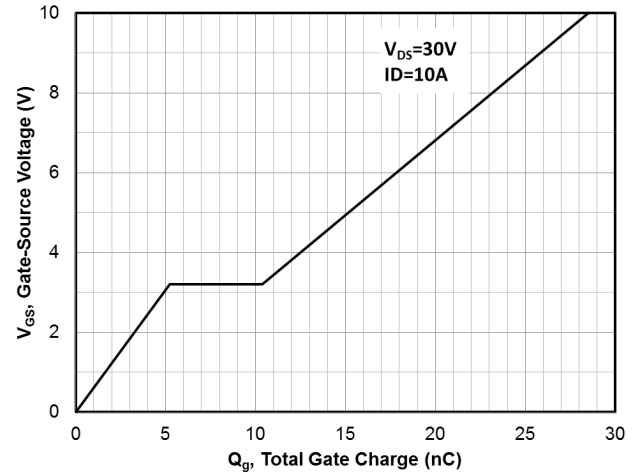
CHARACTERISTICS CURVES

($T_C = 25^\circ\text{C}$ unless otherwise noted)

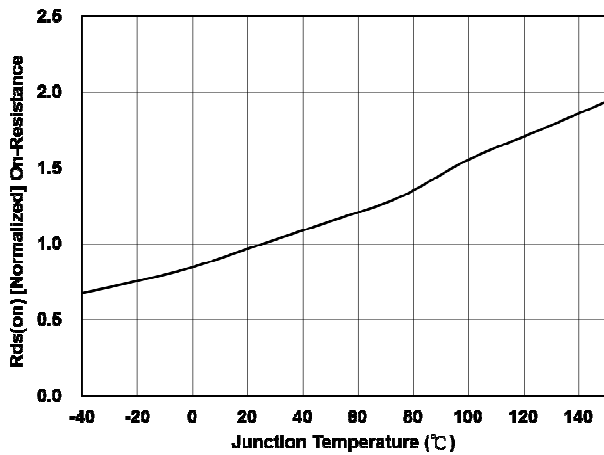
Continuous Drain Current vs. T_C



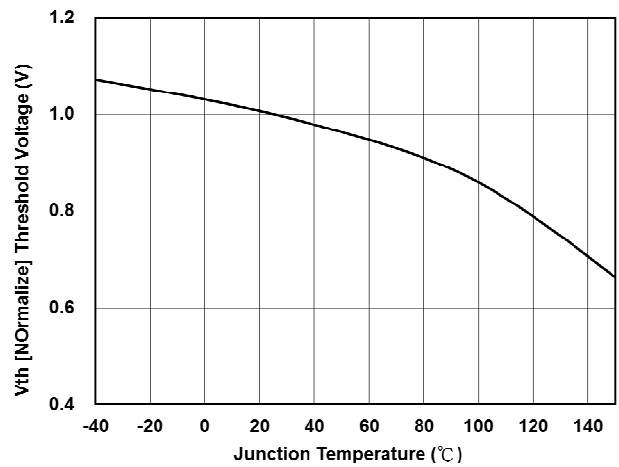
Gate Charge



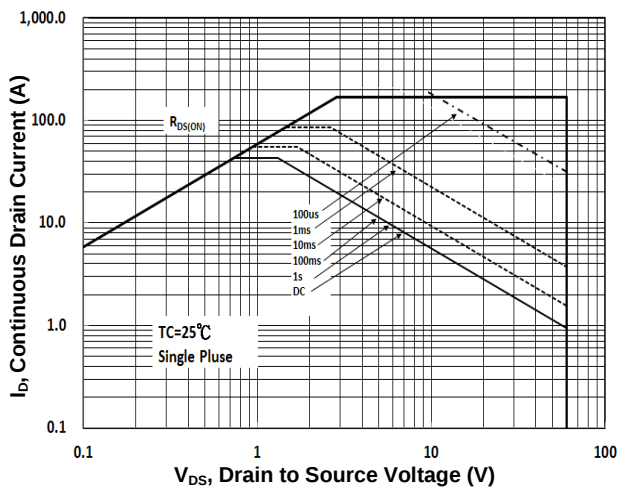
On-Resistance vs. Junction Temperature



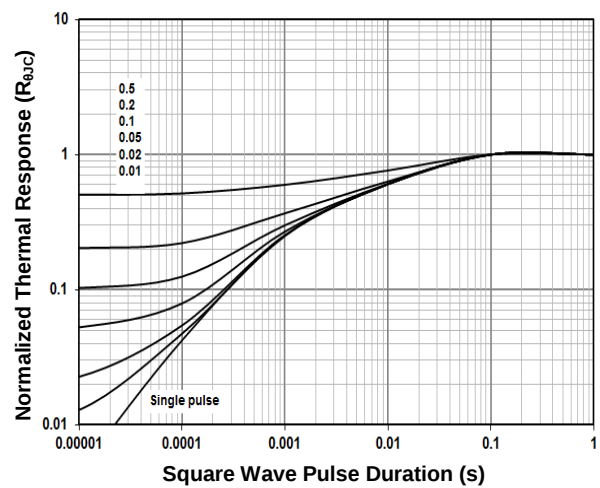
Threshold Voltage vs. Junction Temperature



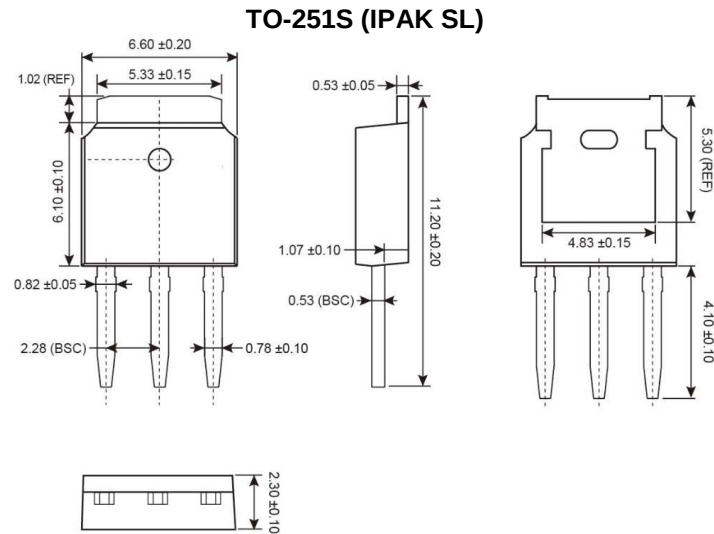
Maximum Safe Operating Area



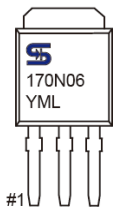
Normalized Thermal Transient Impedance Curve



PACKAGE OUTLINE DIMENSIONS (Unit: Millimeters)



MARKING DIAGRAM

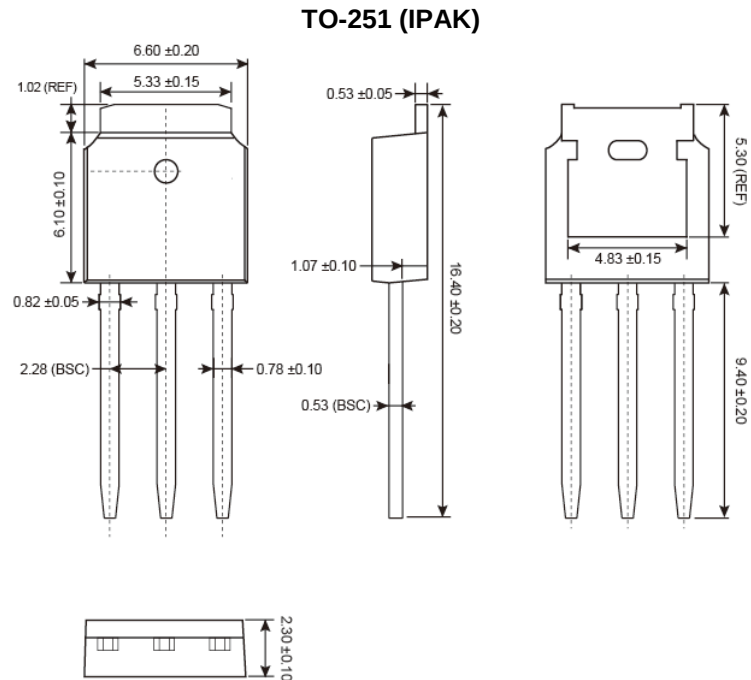


Y = Year Code
M = Month Code for Halogen Free Product

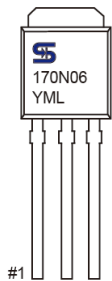
O =Jan	P =Feb	Q =Mar	R =Apr
S =May	T =Jun	U =Jul	V =Aug
W =Sep	X =Oct	Y =Nov	Z =Dec

L = Lot Code (1~9, A~Z)

PACKAGE OUTLINE DIMENSIONS (Unit: Millimeters)



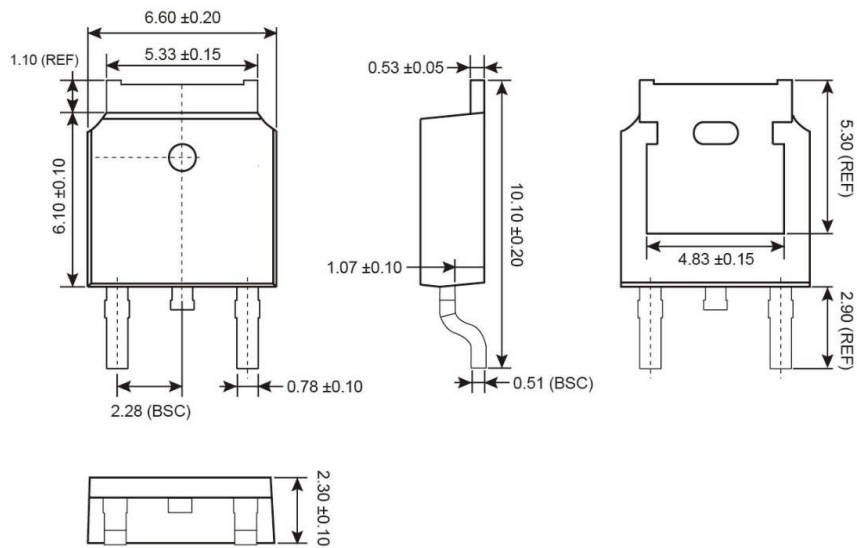
MARKING DIAGRAM



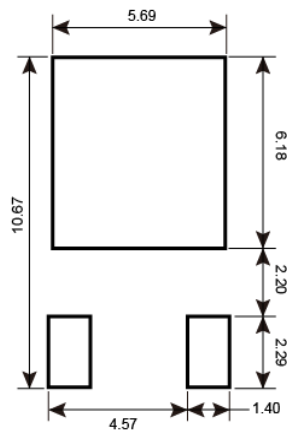
Y = Year Code
M = Month Code for Halogen Free Product
O =Jan **P** =Feb **Q** =Mar **R** =Apr
S =May **T** =Jun **U** =Jul **V** =Aug
W =Sep **X** =Oct **Y** =Nov **Z** =Dec
L = Lot Code (1~9, A~Z)

PACKAGE OUTLINE DIMENSIONS (Unit: Millimeters)

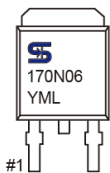
TO-252 (DPAK)



SUGGESTED PAD LAYOUT (Unit: Millimeters)



MARKING DIAGRAM



Y = Year Code

M = Month Code for Halogen Free Product

O =Jan **P** =Feb **Q** =Mar **R** =Apr

S =May **T** =Jun **U** =Jul **V** =Aug

W =Sep **X** =Oct **Y** =Nov **Z** =Dec

L = Lot Code (1~9, A~Z)

Notice

Specifications of the products displayed herein are subject to change without notice. TSC or anyone on its behalf, assumes no responsibility or liability for any errors or inaccuracies.

Information contained herein is intended to provide a product description only. No license, express or implied, to any intellectual property rights is granted by this document. Except as provided in TSC's terms and conditions of sale for such products, TSC assumes no liability whatsoever, and disclaims any express or implied warranty, relating to sale and/or use of TSC products including liability or warranties relating to fitness for a particular purpose, merchantability, or infringement of any patent, copyright, or other intellectual property right.

The products shown herein are not designed for use in medical, life-saving, or life-sustaining applications. Customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify TSC for any damages resulting from such improper use or sale.



**Стандарт
Электрон
Связь**

Мы молодая и активно развивающаяся компания в области поставок электронных компонентов. Мы поставляем электронные компоненты отечественного и импортного производства напрямую от производителей и с крупнейших складов мира.

Благодаря сотрудничеству с мировыми поставщиками мы осуществляем комплексные и плановые поставки широчайшего спектра электронных компонентов.

Собственная эффективная логистика и склад в обеспечивает надежную поставку продукции в точно указанные сроки по всей России.

Мы осуществляем техническую поддержку нашим клиентам и предпродажную проверку качества продукции. На все поставляемые продукты мы предоставляем гарантию .

Осуществляем поставки продукции под контролем ВП МО РФ на предприятия военно-промышленного комплекса России , а также работаем в рамках 275 ФЗ с открытием отдельных счетов в уполномоченном банке. Система менеджмента качества компании соответствует требованиям ГОСТ ISO 9001.

Минимальные сроки поставки, гибкие цены, неограниченный ассортимент и индивидуальный подход к клиентам являются основой для выстраивания долгосрочного и эффективного сотрудничества с предприятиями радиоэлектронной промышленности, предприятиями ВПК и научно-исследовательскими институтами России.

С нами вы становитесь еще успешнее!

Наши контакты:

Телефон: +7 812 627 14 35

Электронная почта: sales@st-electron.ru

Адрес: 198099, Санкт-Петербург,
Промышленная ул, дом № 19, литера Н,
помещение 100-Н Офис 331